TOSHIBA TRANSISTOR SILICON PNP EPITAXIAL TYPE (PCT PROCESS)

## 2SA1162

AUDIO FREQUENCY GENERAL PURPOSE AMPLIFIER APPLICATIONS.

Unit in mm

• High Voltage and High Current

: 
$$V_{CEO} = -50V$$
,  $IC = -150mA$  (Max.)

• Excellent hFE Linearity

$$: h_{FE} (I_C = -0.1 \text{mA}) / h_{FE} (I_C = -2 \text{mA}) = 0.95 \text{ (Typ.)}$$

• High hFE  $: hFE = 70 \sim 400$ 

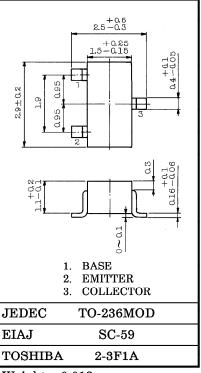
• Low Noise: NF=1dB (Typ.), 10dB (Max.)

• Complementary to 2SC2712

• Small Package

## MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	$v_{\mathrm{CBO}}$	-50	V
Collector-Emitter Voltage	$v_{CEO}$	-50	V
Emitter-Base Voltage	$v_{ m EBO}$	-5	V
Collector Current	$I_{\mathbf{C}}$	-150	mA
Base Current	$I_{ m B}$	-30	mA
Collector Power Dissipation	$P_{\mathbf{C}}$	150	mW
Junction Temperature	$T_{j}$	125	°C
Storage Temperature Range	$\mathrm{T_{stg}}$	-55~125	°C



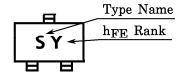
Weight: 0.012g

## ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	$I_{CBO}$	$V_{\mathrm{CB}}\!=\!-50\mathrm{V},~\mathrm{I_E}\!=\!0$	_	_	-0.1	$\mu$ <b>A</b>
Emitter Cut-off Current	$I_{EBO}$	$V_{EB} = -5V, I_C = 0$	_	_	-0.1	$\mu$ <b>A</b>
DC Current Gain	hFE (Note)	$V_{CE} = -6V, I_{C} = -2mA$	70	_	400	
Collector-Emitter Saturation Voltage	V <sub>CE</sub> (sat)	$I_C = -100 \text{mA}, I_B = -10 \text{mA}$	_	-0.1	-0.3	V
Transition Frequency	$ m f_{T}$	$V_{CE} = -10V, I_{C} = -1mA$	80	_	_	MHz
Collector Output Capacitance	$C_{ob}$	$V_{CB} = -10V, I_E = 0, f = 1MHz$	_	4	7	pF
Noise Figure	NF	$V_{\text{CE}}$ =-6V, $I_{\text{C}}$ =0.1mA, f=1kHz, $R_{\text{g}}$ =10k $\Omega$	_	1.0	10	dB

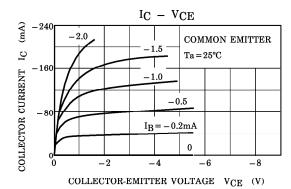
Note: h<sub>FE</sub> Classification O(O): 70~140, Y(Y): 120~240, GR(G): 200~400 () Marking Symbol

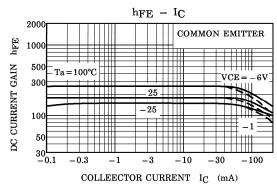
MARKING

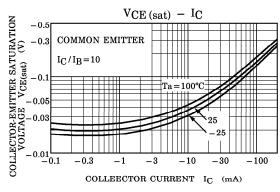


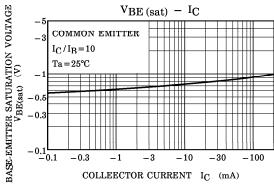
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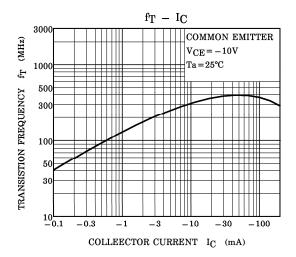
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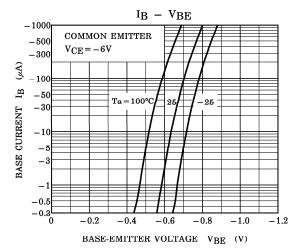


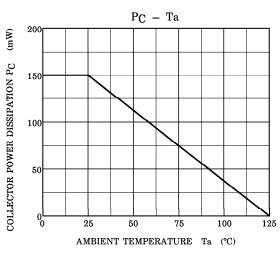












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